AMENDMENTS TO THE CLAIMS

Please amend the claims as follows:

- 1. (withdrawn) An electronic device comprising:
 - a phase change material;
 - a first terminal in electrical communication with said phase change material;
 - a second terminal in electrical communication with said phase change material;
 - a third terminal in electrical communication with said phase change material;
- wherein the electrical resistance measured between said first and second terminals differs from the electrical resistance measured between said first and third terminals.
- 2. (withdrawn) The device of claim 1, wherein said phase change material is a chalcogenide material.
- 3. (withdrawn) The device of claim 1, wherein said phase change material is reversibly transformable between a crystalline phase and an amorphous phase, said crystalline phase and said amorphous phase having different electrical resistances.
- 4. (withdrawn) The device of claim 1, wherein said phase change material comprises S, Se, or Te.
- 5. (withdrawn) The device of claim 4, wherein said phase change material further comprises Ge or Sb.
- 6. (withdrawn) The device of claim 4, wherein said phase change material further comprises As or Si.

- 7. (withdrawn) The device of claim 4, wherein said phase change material further comprises an element selected from the group consisting of Al, In, Bi, Pb, Sn, P, and O.
- 8. (withdrawn) The device of claim 1, wherein said difference in measured electrical resistances is at least a factor of two.
- 9. (withdrawn) The device of claim 1, wherein said difference in measured electrical resistances is at least an order of magnitude.
- 10. (withdrawn) The device of claim 1, wherein said measured electrical resistance between said first and second terminals differs from the electrical resistance measured between said second and third terminals.
- 11. (withdrawn) The device of claim 1, wherein said device is a logic device.
- 12. (withdrawn) The device of claim 11, wherein said logic device is an OR device.
- 13. (withdrawn) The device of claim 11, wherein said logic device is an AND device.
- 14. (withdrawn) The device of claim 1, wherein said phase change material includes a crystalline region and an amorphous region.
- 15. (withdrawn) The device of claim 1, wherein said phase change material includes an amorphous region that resistively shields one of said terminals.
- 16. (withdrawn) The device of claim 15, wherein said resistively shielding amorphous region is in physical contact with said resistively shielded terminal.
- 17. (withdrawn) The device of claim 16, wherein said resistively shielding amorphous region substantially covers said resistively shielded terminal.
- 18. (withdrawn) The device of claim 1, wherein said phase change material includes a continuous crystalline pathway between at least one pair of said terminals.

19. (currently amended) A method of operating an electronic device, said device comprising a phase change material and three or more terminals in electrical communication therewith, a first terminal in electrical communication with said phase change material, a second terminal in electrical communication with said phase change material and a third terminal in electrical communication with said phase change, said method comprising the steps of:

applying a first signal between a first pair of said terminals of said device said first terminal and said second terminal; and

applying a second signal between a second pair of said-terminals of said-device said first terminal and said third terminal; and

measuring the resistance between said second terminal and said third terminal.

- 20. (original) The method of claim 19, wherein one of said first and second signals is an amorphizing signal.
- 21. (original) The method of claim 20, wherein said amorphizing signal forms a resistively shielding amorphous region.
- 22. (original) The method of claim 19, wherein one of said first and second signals is a crystallizing signal.
- 23. (original) The method of claim 22, wherein said crystallizing signal removes a resistively shielding amorphous region.
- 24. (original) The method of claim 19, wherein said first and second signals are electrical signals.
- (original) The method of claim 24 wherein said electrical signals are current pulses.
- 26. (currently amended) The method of claim 19, wherein said first signal modifies the resistance measured between said first pair of and second terminals.

- 27. (currently amended) The method of claim 26, wherein said first signal does not substantially change the resistance measured between said second pair of first and third terminals.
- 28. (currently amended) The method of claim 26, wherein said second signal modifies the resistance measured between said second pair of first and third terminals.
- 29. (cancelled)
- 30. (currently amended) The method of claim 19, further comprising the step of measuring the current between a third pair of said second and third terminals.